

PNP General Purpose Transistor

UMT3906/SST3906/MMST3906

●Features

- 1) $BV_{CEO} > -40V$ ($I_C = -1mA$)
- 2) Complements the T3904/SST3904/MMST3909.
- 3) Low capacitance.

●Package, marking, and packaging specifications

| Type | UMT3906 | SST3906 | MMST3906 |
|------------------------------|---------|---------|----------|
| Packaging type | UMT3 | SST3 | SMT3 |
| Marking | R2A | R2A | R2A |
| Code | T106 | T116 | T146 |
| Basic ordering unit (pieces) | 3000 | 3000 | 3000 |

●Absolute maximum ratings (Ta=25°C)

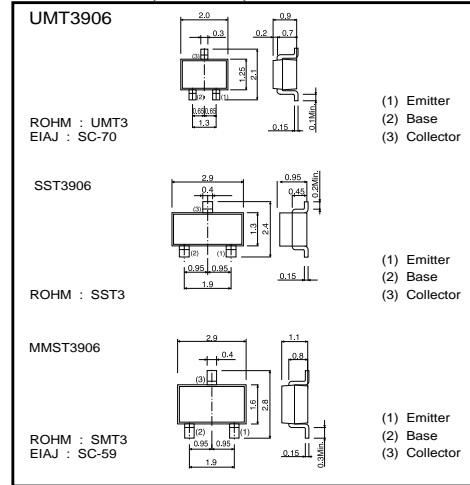
| Parameter | Symbol | Limits | Unit | |
|-----------------------------|-----------------------------|-------------|------|-----|
| Collector-base voltage | V_{CBO} | -40 | V | |
| Collector-emitter voltage | V_{CEO} | -40 | V | |
| Emitter-base voltage | V_{EBO} | -5 | V | |
| Collector current | I_C | -0.2 | A | |
| Collector Power dissipation | UMT3906 SST3906,MMST3906 | P_d | 6.2 | W |
| | SST3906,MMST3906 | | 0.35 | W * |
| Junction temperature | T_j | 150 | °C | |
| Storage temperature | T_{stg} | -55 to +150 | °C | |

* When mounted on a 7×5×0.6mm ceramic board.

●Electrical characteristics (Ta=25°C)

| Parameter | Symbol | Min. | Typ. | Max. | Unit | Conditions |
|--------------------------------------|---------------|-------|------|-------|------|---|
| Collector-base breakdown voltage | BV_{CBO} | -40 | - | - | V | $I_C = -10\mu A$ |
| Collector-emitter breakdown voltage | BV_{CEO} | -40 | - | - | V | $I_C = -1mA$ |
| Emitter-base breakdown voltage | BV_{EBO} | -5 | - | - | V | $I_E = -10\mu A$ |
| Collector cutoff current | I_{CES} | - | - | -50 | nA | $V_{CB} = -30V$ |
| Emitter cutoff current | I_{EBO} | - | - | -50 | nA | $V_{EB} = -3V$ |
| Collector-emitter saturation voltage | $V_{CE(sat)}$ | - | - | -0.25 | V | $I_C/I_B = -10mA/-1mA$ |
| | | - | - | -0.4 | V | $I_C/I_B = -50mA/-5mA$ |
| Base-emitter saturation voltage | $V_{BE(sat)}$ | -0.65 | - | -0.85 | V | $I_C/I_B = -10mA/-1mA$ |
| | | - | - | -0.95 | V | $I_C/I_B = -50mA/-5mA$ |
| DC current transfer ratio | h_{FE} | 60 | - | - | - | $V_{CE} = -1V, I_C = -0.1mA$ |
| | | 80 | - | - | - | $V_{CE} = -1V, I_C = -1mA$ |
| | | 100 | - | 300 | - | $V_{CE} = -1V, I_C = -10mA$ |
| | | 60 | - | - | - | $V_{CE} = -1V, I_C = -50mA$ |
| | | 30 | - | - | - | $V_{CE} = -1V, I_C = -100mA$ |
| Transition frequency | f_T | 250 | - | - | MHz | $V_{CE} = -20V, I_E = 10mA, f = 100MHz$ |
| Collector output capacitance | C_{ob} | - | - | 4.5 | pF | $V_{CB} = -10V, f = 100kHz, I_E = 0A$ |
| Emitter input capacitance | C_{ib} | - | - | 10 | pF | $V_{CB} = -0.5V, f = 100kHz, I_C = 0A$ |
| Delay time | t_d | - | - | 35 | ns | $V_{CC} = -3V, V_{BE(OFF)} = -0.5V, I_C = -10mA, I_{B1} = -1mA$ |
| Rise time | t_r | - | - | 35 | ns | $V_{CC} = -3V, V_{BE(OFF)} = -0.5V, I_C = -10mA, I_{B1} = -1mA$ |
| Storage time | t_{stg} | - | - | 225 | ns | $V_{CC} = -3V, I_C = -10mA, I_{B1} = -I_{B2} = -1mA$ |
| Fall time | t_f | - | - | 75 | ns | $V_{CC} = -3V, I_C = -10mA, I_{B1} = -I_{B2} = -1mA$ |

●Dimensions (Unit : mm)



Transistors

●Electrical characteristics curves

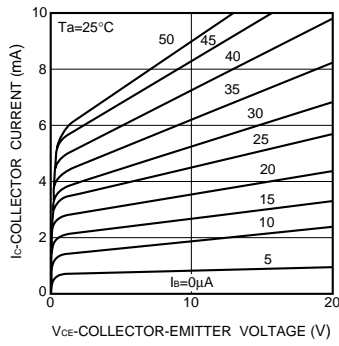


Fig.1 Grounded emitter output characteristics

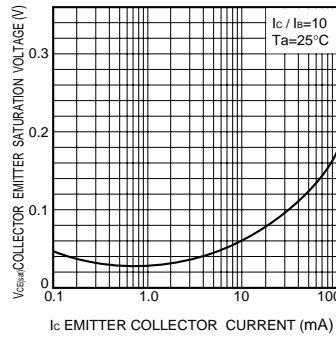


Fig.2 Collector-emitter saturation voltage vs. collector current

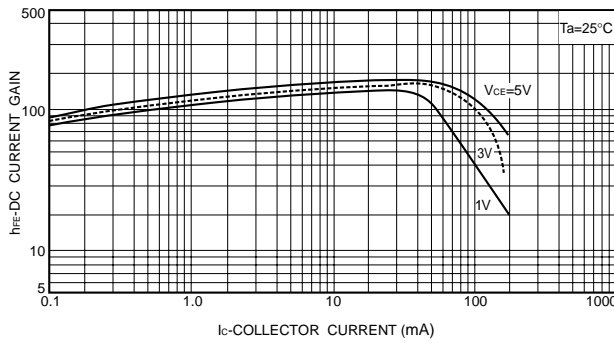


Fig.3 DC current gain vs. collector current (I)

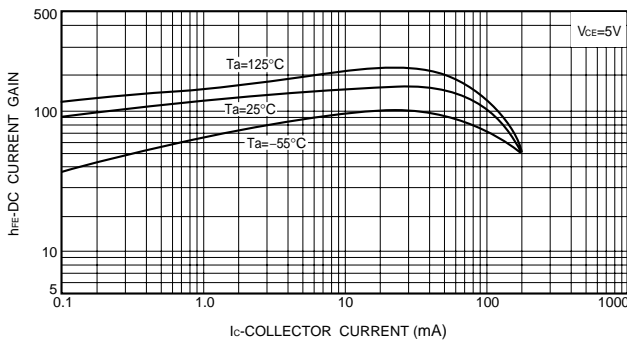


Fig.4 DC current gain vs. collector current (II)

Transistors

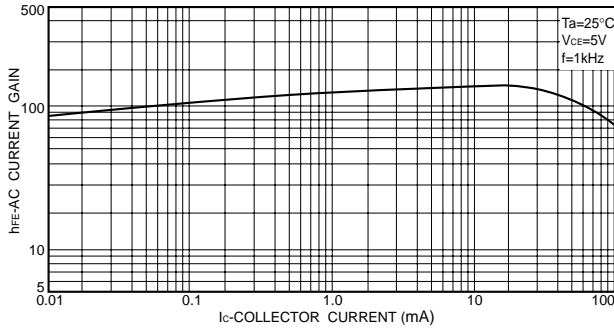


Fig.5 AC current gain vs. collector current

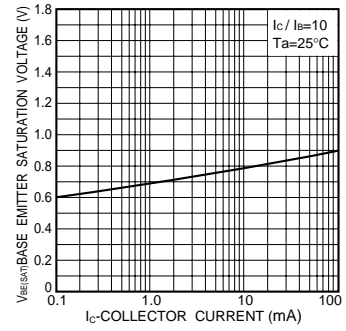


Fig.6 Base-emitter saturation voltage vs. collector current

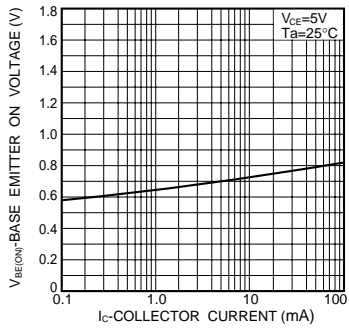


Fig.7 Grounded emitter propagation characteristics

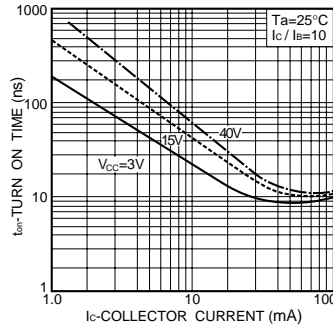


Fig.8 Turn-on time vs. collector current

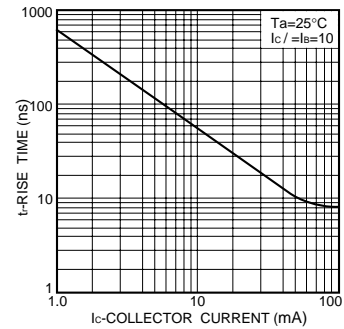


Fig.9 Rise time vs. collector current

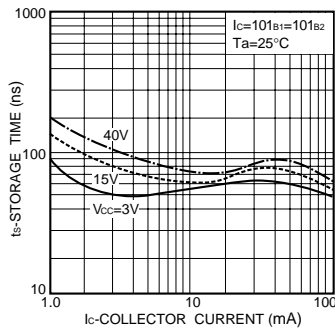


Fig.10 Storage time vs. collector current

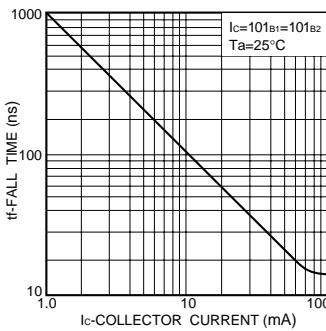


Fig.11 Fall time vs. collector current

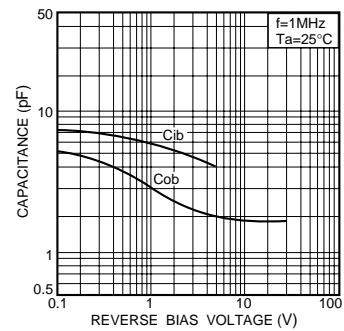


Fig.12 Input / output capacitance vs. voltage

Transistors

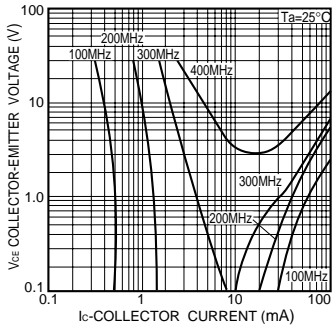


Fig.13 Gain bandwidth product

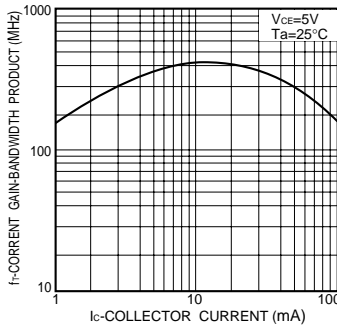


Fig.14 Gain bandwidth product vs. collector current

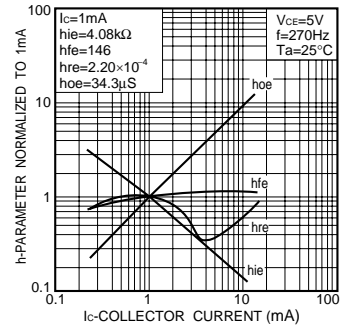


Fig.15 h parameter vs. collector current

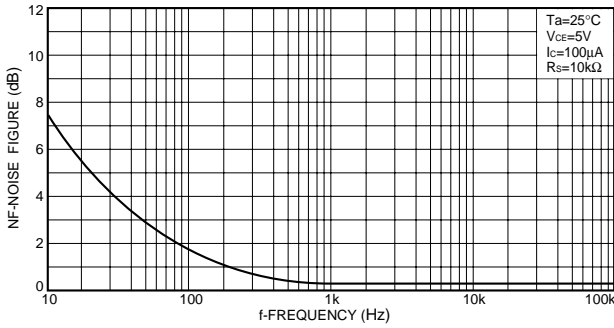


Fig.16 Noise vs. collector current

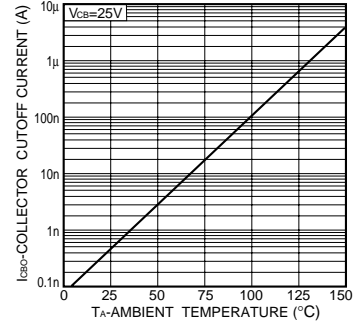


Fig.17 Noise characteristics (I)

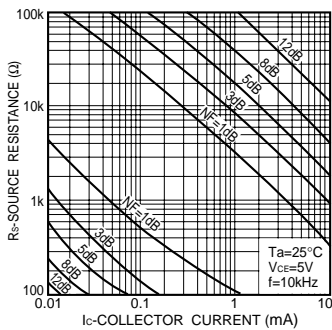


Fig.18 Noise characteristics (II)

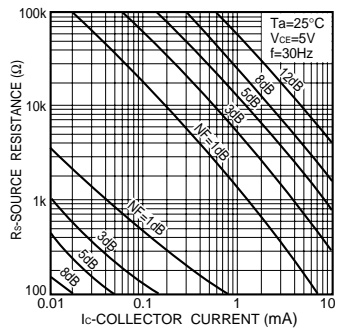


Fig.19 Noise characteristics (III)

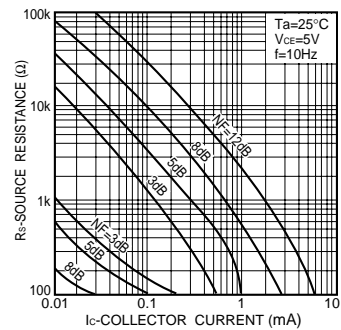


Fig.20 Noise characteristics (IV)

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